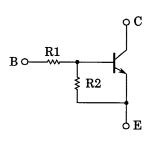
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1101,RN1102,RN1103 RN1104,RN1105,RN1106

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2101~RN2106

## **Equivalent Circuit and Bias Resister Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN1101	4.7	4.7
RN1102	10	10
RN1103	22	22
RN1104	47	47
RN1105	2.2	47
RN1106	4.7	47

# 1. BASE 2. EMITTER 3. COLLECTOR JEDEC — EIAJ — TOSHIBA 2-2H1A

Weight: 2.4mg

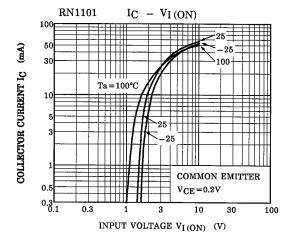
### Maximum Ratings (Ta = 25°C)

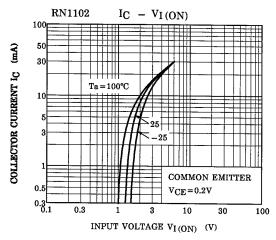
Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1101~1106	$V_{CBO}$	50	V	
Collector-emitter voltage	1441101-1100	V <sub>CEO</sub>	50	V	
Emitter-base voltage	RN1101~1104	V <sub>EBO</sub>	10	V	
	RN1105, 1106	▼EBO	5		
Collector current		I <sub>C</sub>	100	mA	
Collector power dissipation	RN1101~1106	PC	100	mW	
Junction temperature	RIVITOT~1100	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

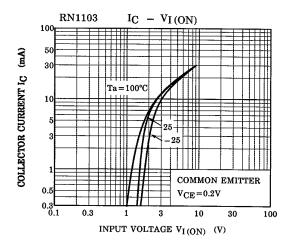


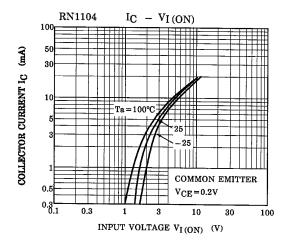
# Electrical Characteristics (Ta = 25°C)

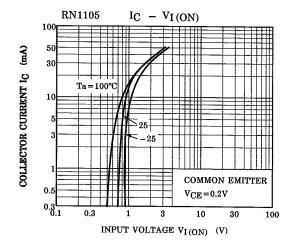
Character	istic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1101~1106	I <sub>CBO</sub>		V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
	KNTTOT~TTOO		_	V <sub>CE</sub> =50V, I <sub>B</sub> = 0	_	_	500	
Emitter cut-off current	RN1101	I <sub>EBO</sub>	_	V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	mA
	RN1102				0.38	_	0.71	
	RN1103				0.17	_	0.33	
	RN1104				0.082	_	0.15	
	RN1105			V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1106				0.074	_	0.138	
	RN1101				30	_	_	_
	RN1102				50	_	_	
DO	RN1103	L		)/ - 5\/   - 40A	70	_	_	
DC current gain	RN1104	h <sub>FE</sub>		$V_{CE}$ = 5V, $I_C$ = 10mA	80	_	_	
	RN1105				80	_	_	
	RN1106				80	_	_	
Collector-emitter saturation voltage	RN1101~1106	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
Input voltage (ON)	RN1101	V <sub>I (ON)</sub>		V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	V
	RN1102		_		1.2	_	2.4	
	RN1103				1.3	_	3.0	
	RN1104				1.5	_	5.0	
	RN1105				0.6	_	1.1	
	RN1106				0.7	_	1.3	
Innut valtage (OFF)	RN1101~1104	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	
Input voltage (OFF)	RN1105, 1106				0.5	_	0.8	V
Transition frequency	RN1101~1106	f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector Output capacitance	RN1101~1106	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MH <sub>z</sub>	_	3	6	pF
Input resistor	RN1101	R1			3.29	4.7	6.11	
	RN1102				7	10	13	kΩ
	RN1103				15.4	22	28.6	
	RN1104		_		32.9	47	61.1	
	RN1105				1.54	2.2	2.86	
	RN1106				3.29	4.7	6.11	
Resistor ratio	RN1101~1104				0.9	1.0	1.1	
	RN1105	R1/R2	_		0.0421	0.0468	0.0515	
	RN1106				0.09	0.1	0.11	

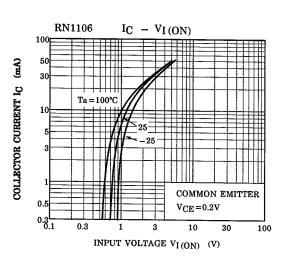


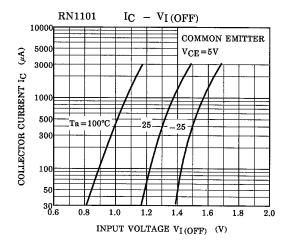


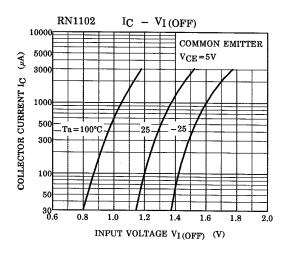


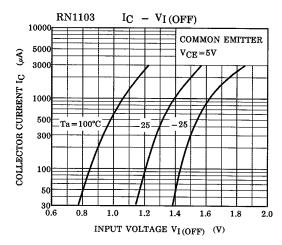


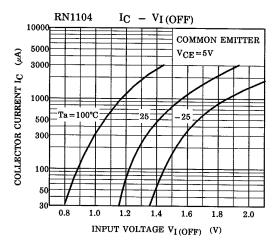


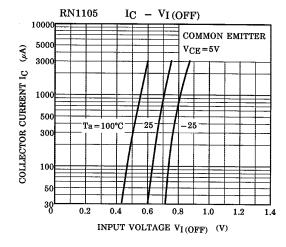


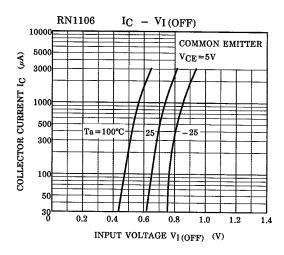


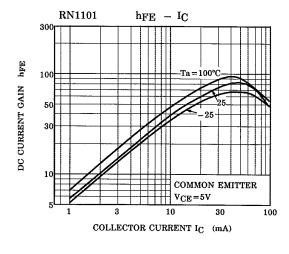


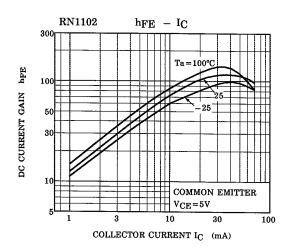


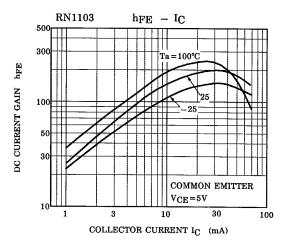


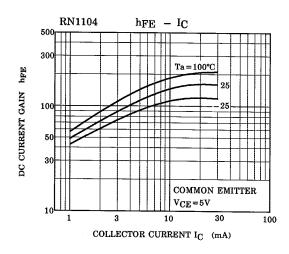


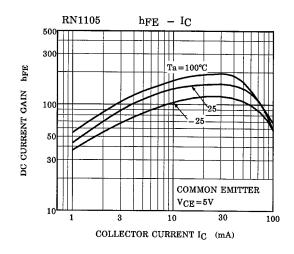


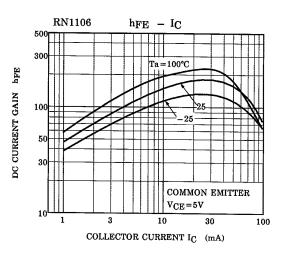














Type Name	Marking
RN1101	Type Name
RN1102	Type Name  X B  H H
RN1103	Type Name  X C  H H
RN1104	Type Name X D
RN1105	Type Name  X E
RN1106	Type Name  X F

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